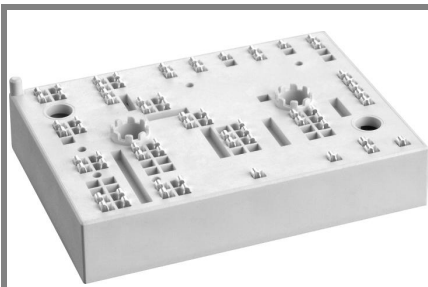


SKiiP 39AC12T4V1



MiniSKiiP®3

3-phase bridge inverter

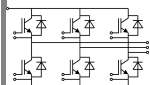
SKiiP 39AC12T4V1

Target Data

Features

- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications

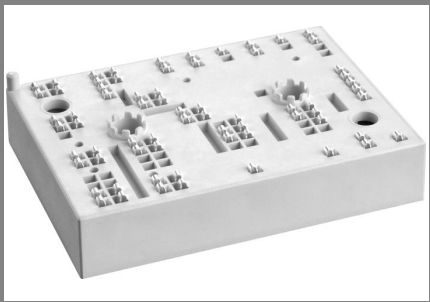


AC

Absolute Maximum Ratings			$T_s = 25\text{ }^{\circ}\text{C}$, unless otherwise specified	
Symbol	Conditions		Values	Units
IGBT				
V_{CES}	$T_j = 25\text{ }^{\circ}\text{C}$		1200	V
I_C	$T_j = 175\text{ }^{\circ}\text{C}$	$T_c = 25\text{ }^{\circ}\text{C}$	171	A
		$T_c = 70\text{ }^{\circ}\text{C}$	135	A
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$		450	A
V_{GES}			± 20	V
t_{psc}	$V_{CC} = 600\text{ V}$; $V_{GE} \leq 20\text{ V}$; $T_j = 150\text{ }^{\circ}\text{C}$ $V_{CES} < 1200\text{ V}$		10	μs
Inverse Diode				
I_F	$T_j = 175\text{ }^{\circ}\text{C}$	$T_c = 25\text{ }^{\circ}\text{C}$	144	A
		$T_c = 70\text{ }^{\circ}\text{C}$	128	A
I_{FRM}	$I_{CRM} = 3 \times I_{Cnom}$		450	A
I_{FSM}	$t_p = 10\text{ ms}$; sin $T_j = 150\text{ }^{\circ}\text{C}$		900	A
Module				
$I_{t(RMS)}$			160	A
T_{vj}			-40...+175	$^{\circ}\text{C}$
T_{stg}			-40...+125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.		2500	V

Characteristics			T _s = 25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 6 mA		5	5,8	6,5	V
I _{CES}	V _{GE} = V, V _{CE} = V _{CES} T _j = °C					mA
V _{CE0}	T _j = 25 °C			1,1	1,3	V
	T _j = 150 °C			1	1,2	V
r _{CE}	V _{GE} = 15 V T _j = 25°C			5	5	mΩ
	T _j = 150°C			8,3	8,3	mΩ
V _{CE(sat)}	I _{Cnom} = 150 A, V _{GE} = 15 V T _j = 25°C _{chiplev.}			1,8	2	V
	T _j = 150°C _{chiplev.}			2,2	2,4	V
C _{ies}	V _{CE} = 25, V _{GE} = 0 V f = 1 MHz					nF
C _{oes}						nF
C _{res}						nF
R _{Gint}	T _j = 25 °C			5		Ω
t _{d(on)}	R _{Gon} =	V _{CC} = V I _{Cnom} = A T _j = °C V _{GE} = ±15V	9			ns
t _r						ns
E _{on}	mJ					
t _{d(off)}	R _{Goff} =		21			ns
t _f						ns
E _{off}						mJ
R _{th(j-s)}	per IGBT			0,33		K/W

SKiiP 39AC12T4V1



MiniSKiiP^{®3}

3-phase bridge inverter

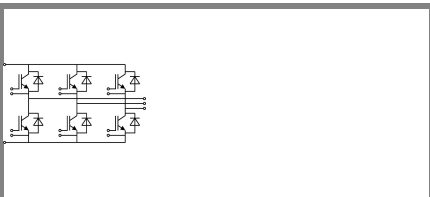
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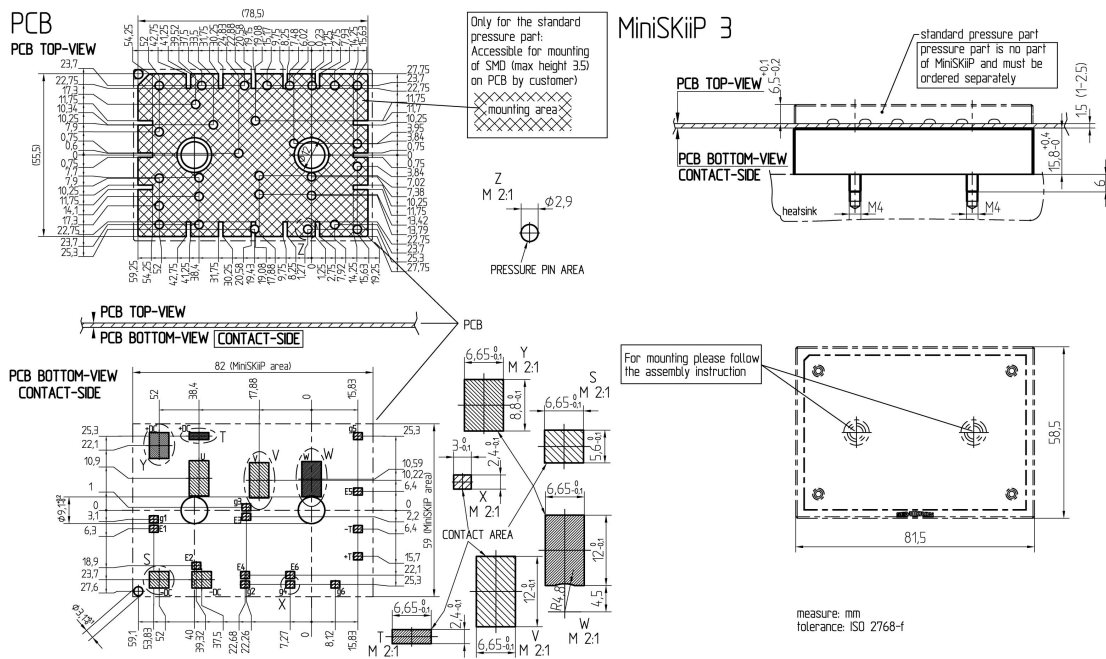


AC

Characteristics						
Symbol	Conditions		min.	typ.	max.	Units
Inverse Diode						
V _F = V _{EC}	I _{Fnom} = 150 A; V _{GE} = 15 V	T _j = 25 °C _{chiplev.}		2,15	2,45	V
		T _j = 150 °C _{chiplev.}		2,05	2,4	V
V _{F0}		T _j = 25 °C		1,3	1,5	V
		T _j = 150 °C		0,9	1,1	V
r _F		T _j = 25 °C		5,7	6,3	mΩ
		T _j = 150 °C		7,7	8,6	mΩ
I _{RRM}	I _{Fnom} = 150 A	T _j = 150 °C				A
Q _{rr}						μC
E _{rr}	V _{GE} = ±15V			11,3		mJ
R _{th(j-s)}	per diode			0,4		K/W
M _s	to heat sink		2		2,5	Nm
w				95		g
Temperature sensor						
R _{ts}	3%, Tr = 25°C			1000		Ω
R _{ts}	3%, Tr = 100°C			1670		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.



case

